

Technical Data Data Sheet N1086, Rev. A **Green Products**

MURF1620CTR ULTRAFAST PLASTIC RECTIFIER

Applications:

- Switching Power Supply
- Power Switching Circuits
- General Purpose

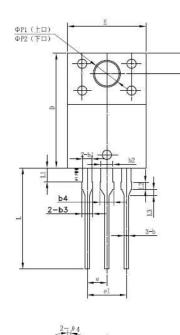
Features:

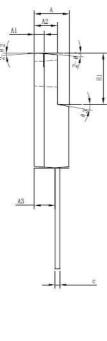
- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot

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• Additional testing can be offered upon request

Mechanical Dimensions: In mm

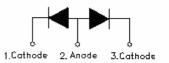




SYMBOL	MIN.	TYP.	MAX.	
Α	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3 b	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
b3	1.20	1.30	1.45	
b4	1.60	1.70	1.85	
С	0.55	0.60	0.75	
c D E	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е		2.55		
e1		5.10		
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
L1	1.60	1.80	2.00 1.20	
L2	0.80	1.00		
L3	0.60	0.80	1.00	
ΦΡ1(上口)	3.30	3.50	3.70	
ΦΡ2(下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		

ITO-220AB(HD)

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Marking Diagram:



Where XXXXX is YYWWL

MUR	= Device Type
F	= Package type
16	= Forward Current (16A)
20	= Reverse Voltage (200V)
CTR	= Configuration
SSG	= SSG
ΥY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping	
MURF1620CTR	ITO-220AB	FOres / tube	
	(Pb-Free)	50pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.



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Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	MURF1620CTR	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{rrm} V _{rwm} V _r	200	V
Average Rectified Output Current @T _A =105°C	lo	16.0	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	125	A
Forward Voltage (per element) $@I_F = 8.0A, T_J=25$ °C	V _{FM1}	1.5	V
Peak Reverse Current $@T_A = 25$ °CAt Rated DC Blocking Voltage $@T_A = 125$ °C	I _R	10 500	μA
Maximum Reverse Recovery Time (Note 1)	Trr	35	ns
Typical Junction Capacitance (Note 2)	CJ	80	pF
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	C
Approximate Weight	wt	2.0	g
Case Style	ITO-220AB		

Note: 1.Measured with $I_F=0.5A$; $I_R=1.0A$; $I_{RR}=0.25A$.

2.Measured at 1.0MHz and applied reverse voltage of 4.0V D.C.

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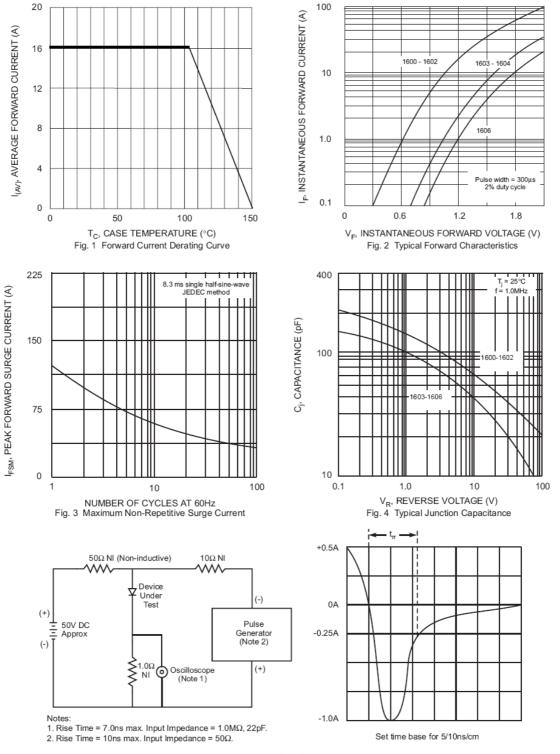


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

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